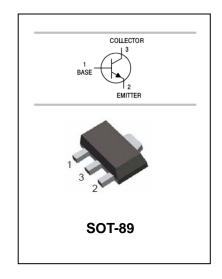
BL Galaxy Electrical

NPN Silicon Epitaxial Planar Transistor

KTC4373

FEATURES

- High transition frequency: V_{CEO}=120V.
- Lead-free
- High voltage:V_{CE(sat)}=0.5V(Max).
- P_C=1W(Mounted on ceramic substrate).
- Small flat package.
- Complementary: KTA1661.



APPLICATIONS

- Power amplifier application.
- Power switching application.

ORDERING INFORMATION

Type No.	Marking	Package Code
KTC4373	CO/CY	SOT-89

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	120	< >
V _{CEO}	Collector-Emitter Voltage	120	V
V _{EBO}	Emitter-Base Voltage	5	<
I _C	Collector Current -Continuous	800	mA
I _B	Base current	160	mA
P _C	Collector Dissipation	500	mW
$T_{j,}T_{stg}$	Junction and Storage Temperature	-55~150	$^{\circ}$

Document number: BL/SSSTG014

Rev.A



NPN Silicon Epitaxial Planar Transistor

KTC4373

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V _{(BR)CBO}	$I_C=1$ mA, $I_E=0$	120			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA,I _B =0	120			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =1mA,I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =120V,I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _C =0			0.1	μA
DC current gain	h _{FE}	V _{CE} =5V,I _C =100mA	80		240	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =500mA, I _B = 50mA			1.0	V
Base-emitter voltage	V_{BE}	V _{CE} =5V, I _B = 500mA			1.0	V
Transition frequency	f _T	V _{CE} =5V, I _C = 0.1A		120		MHz
Collector output capacitance	C _{ob}	V _{CB} =10V,I _E =0,f=1MHz			30	pF

CLASSIFICATION OF $h_{\text{FE}(1)}$

Rank	0	Υ
Range	80-160	120-240
MARKING	СО	CY

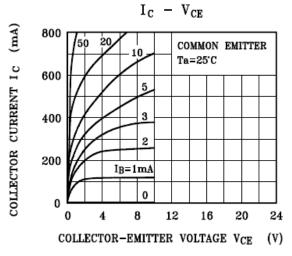
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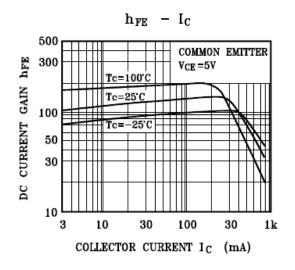
Rev.A

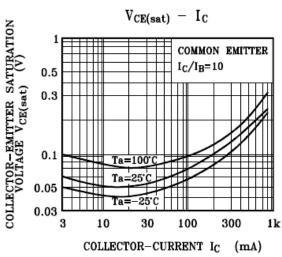
NPN Silicon Epitaxial Planar Transistor

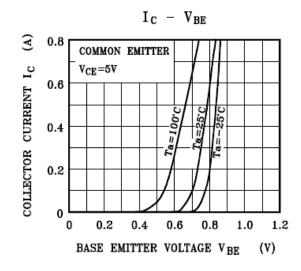
KTC4373

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

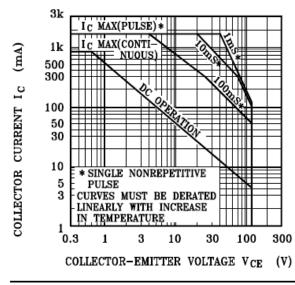


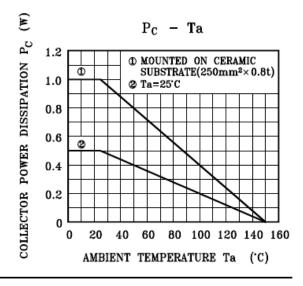












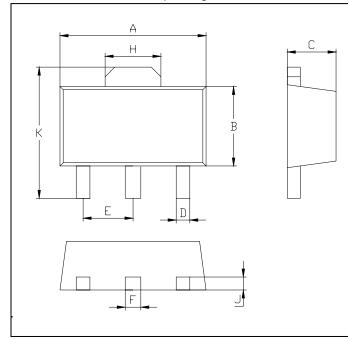
NPN Silicon Epitaxial Planar Transistor

KTC4373

PACKAGE OUTLINE

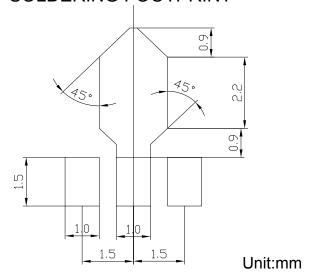
Plastic surface mounted package





SOT-89		
Dim	Min	Max
Α	4.5	4.7
В	2.3	2.7
С	1.5Typical	
D	0.35	0.55
E	1.4	1.6
F	0.4 0.6	
Н	1.55	1.75
J	0.4Typical	
K	4.15	4.25
All Dimensions in mm		

SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
KTC4373	SOT-89	1000/Tape&Reel

www.s-manuals.com